

# 1SP0335x2x1-FZ750R65KE3 and 1SP0335x2x1C-FZ750R65KE3 Data Sheet

Compact, high-performance, plug-and-play single-channel IGBT driver based on SCALE™-2 technology for individual and parallel-connected modules in 2-level, 3-level and multilevel converter topologies

## Abstract

The SCALE™-2 plug-and-play driver 1SP0335x2x1-FZ750R65KE3 / 1SP0335x2x1C-FZ750R65KE3 (Coated version using ELPEGUARD SL 1307 FLZ/2 from Lackwerke Peters) is a compact single-channel intelligent gate driver designed for Infineon's IGBTs FZ750R65KE3(T). The master driver 1SP0335x2M1(C)-FZ750R65KE3 features a fiber-optic interface. It can be used as stand-alone driver or in conjunction with up to three 1SP0335D2S1(C)-FZ750R65KE3 slaves to drive up to four parallel-connected IGBT modules of type FZ750R65KE3(T).

The DC/DC power supply must be purchased as a separate unit (one per master driver).

For drivers adapted to other types of high-power and high-voltage IGBT modules, refer to:

[www.power.com/igbt-driver/go/plug-and-play](http://www.power.com/igbt-driver/go/plug-and-play)

## Features

- ✓ Plug-and-play solution
- ✓ Allows parallel connection of IGBT modules
- ✓ For 2-level, 3-level and multilevel topologies
- ✓ Fiber-optic links (master)
- ✓ Built-in interface to 1SP0335D2S1 (slave)
- ✓ Duty cycle 0...100%
- ✓ Dynamic Advanced Active Clamping DA<sup>2</sup>C
- ✓ Dynamic IGBT short-circuit protection
- ✓ Monitoring of supply voltage
- ✓ Monitoring of gate voltage
- ✓ Extremely reliable; long service life
- ✓ Shortens application development time
- ✓ Suitable for FZ750R65KE3(T)

## Applications

- ✓ Traction
- ✓ Railroad power supplies
- ✓ Light rail vehicles
- ✓ HVDC
- ✓ Flexible AC transmission systems (FACTS)
- ✓ Medium-voltage converters
- ✓ Industrial drives
- ✓ Wind-power converters
- ✓ Medical applications
- ✓ Research
- ✓ And many others

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## Data Sheet

### Safety Notice!

The data contained in this data sheet is intended exclusively for technically trained staff. Handling all high-voltage equipment involves risk to life. Strict compliance with the respective safety regulations is mandatory!

Any handling of electronic devices is subject to the general specifications for protecting electrostatic-sensitive devices according to international standard IEC 60747-1, Chapter IX or European standard EN 100015 (i.e. the workplace, tools, etc. must comply with these standards). Otherwise, this product may be damaged.

### Important Product Documentation

This data sheet contains only product-specific data. For a detailed description, must-read application notes and common data that apply to the whole series, please refer to the "Description & Application Manual for 1SP0335 SCALE-2 IGBT Drivers" on [www.power.com/igbt-driver/go/1SP0335](http://www.power.com/igbt-driver/go/1SP0335).

When applying SCALE-2 plug-and-play drivers, please note that these drivers are specifically adapted to a particular type of IGBT module. Therefore, the type designation of SCALE-2 plug-and-play drivers also includes the type designation of the corresponding IGBT module. These drivers are not valid for IGBT modules other than those specified. Incorrect use may result in failure.

### Mechanical Dimensions

Dimensions: Refer to the relevant "Description and Application Manual"

Mounting principle: Connected to IGBT module with screws

### Fiber-Optic Interfaces (1SP0335x2M1(C))

Interface	Remarks	Part type #
Drive signal input	1SP0335V, fiber-optic receiver (Notes 1, 2)	HFBR-2522ETZ
Drive signal input	1SP0335S, fiber-optic receiver (Notes 1, 2)	HFBR-2412Z
Status output	1SP0335V, fiber-optic transmitter (Notes 1, 3)	HFBR-1522ETZ
Status output	1SP0335S, fiber-optic transmitter (Notes 1, 3)	HFBR-1412Z

### Electrical Connectors

Interface	Remarks	Part type #
Power supply connector X1	On-board connector (Note 4)	214012
Bus connectors X2 and X3	On-board connectors (Note 5)	214013

## Data Sheet

### Absolute Maximum Ratings

Parameter	Remarks	Min	Max	Unit
Supply voltage $V_{DC}$	VDC to COM	0	30	V
Average supply current $I_{DC}$	1SP0335x2M1(C) only (Note 6)		215	mA
Average supply current $I_{DC}$	1SP0335x2M1(C) with three 1SP0335D2S1 (Note 6)		740	mA
Gate output power	1SP0335x2M1(C), $T_a < 70^\circ\text{C}$ (Note 7)		3.5	W
	1SP0335x2M1(C), $T_a = 85^\circ\text{C}$ (Note 7)		2.5	W
Gate output power	1SP0335D2S1(C), $T_a < 70^\circ\text{C}$ (Note 8)		3.3	W
	1SP0335D2S1(C), $T_a = 85^\circ\text{C}$ (Note 8)		2.3	W
Switching frequency $f$	1SP0335x2M1(C), $T_a < 70^\circ\text{C}$		4.9	kHz
	1SP0335x2M1(C), $T_a = 85^\circ\text{C}$		3.4	kHz
Switching frequency $f$	1SP0335D2S1(C), $T_a < 70^\circ\text{C}$		4.6	kHz
	1SP0335D2S1(C), $T_a = 85^\circ\text{C}$		3.1	kHz
Gate peak current $I_{out}$	Note 9	-35	+35	A
DC-link voltage	Switching operation (Note 10)		4400	V
	Off state (Note 11)		5200	V
Operating voltage	Collector-emitter voltage		6500	$V_{peak}$
Max. emitter-emitter voltage	Between parallel connected drivers (Note 12)		200	$V_{peak}$
$ dV/dt $	Between parallel connected drivers (Note 13)		50	kV/ $\mu\text{s}$
Max. interface current	X2 and X3, total RMS value (Note 14)		4	$A_{rms}$
	X2 and X3, total peak value (Note 14)		20	$A_{peak}$
Operating temperature		-40	85	$^\circ\text{C}$
Storage temperature	Note 28	-40	50	$^\circ\text{C}$
Surface temperature	Only 1SP0335x2x1C-FZ750R65KE3 (Note 29)		125	$^\circ\text{C}$

### Recommended Operating Conditions

Power Supply	Remarks	Min	Typ	Max	Unit
Supply voltage $V_{DC}$	To COM	23.5	25	26.5	V

## Data Sheet

<b>Electrical Characteristics</b>
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All data refer to +25°C and  $V_{DC} = 25V$  unless otherwise specified

<b>Power Supply</b>	<b>Remarks</b>	<b>Min</b>	<b>Typ</b>	<b>Max</b>	<b>Unit</b>
Supply current $I_{DC}$	Without load, only 1SP0335x2M1(C)		45		mA
	Without load, per additional 1SP0335D2S1(C)		20		mA
<b>Power Supply Monitoring</b>	<b>Remarks</b>	<b>Min</b>	<b>Typ</b>	<b>Max</b>	<b>Unit</b>
Supply threshold $V_{iso}-V_{ee}$	Clear fault	12.1	12.6	13.1	V
	Set fault (Note 15)	11.5	12.0	12.5	V
Monitoring hysteresis	Set/clear fault	0.35			V
Supply threshold $V_{ee}-V_{COM}$	Clear fault	5	5.15	5.3	V
	Set fault (Note 15)	4.7	4.85	5	V
Monitoring hysteresis	Set/clear fault	0.15			V
<b>Bus to 1SP0335D2S1(C)</b>	<b>Remarks</b>	<b>Min</b>	<b>Typ</b>	<b>Max</b>	<b>Unit</b>
Supply voltage			VDC		V
Turn-off command	To COM		0		V
Turn-on command	To COM		15		V
<b>Gate Monitoring</b>	<b>Remarks</b>	<b>Min</b>	<b>Typ</b>	<b>Max</b>	<b>Unit</b>
Turn-on threshold $V_{GE,on,min}$	$G_{mean}$ to E, set fault (Note 16)		12.9		V
Turn-off threshold $V_{GE,off,max}$	$G_{mean}$ to E, set fault (Note 16)		-7.6		V
Filter delay	Turn-on (Note 16)		28		µs
	Turn-off (Note 16)		42		µs
<b>Short-circuit Protection</b>	<b>Remarks</b>	<b>Min</b>	<b>Typ</b>	<b>Max</b>	<b>Unit</b>
Static Vce-monitoring threshold	Between auxiliary terminals (Note 17)		247		V
Response time	DC-link voltage = 4400V (Note 18)		5.9		µs
	DC-link voltage = 3000V (Note 18)		6		µs
	DC-link voltage = 2200V (Note 18)		6.4		µs
	DC-link voltage = 1500V (Note 18)		10.2		µs
	DC-link voltage = 1500V (Note 18)		10.2		µs
Delay to IGBT turn-off	After the response time (Note 19)		0.3		µs
<b>Timing Characteristics</b>	<b>Remarks</b>	<b>Min</b>	<b>Typ</b>	<b>Max</b>	<b>Unit</b>
Turn-on delay $t_{d(on)}$	Note 20		190		ns
Turn-off delay $t_{d(off)}$	Note 20		185		ns
Output rise time $t_{r(out)}$	G to E (Note 21)		9		ns
Output fall time $t_{f(out)}$	G to E (Note 21)		30		ns

## Data Sheet

Timing Characteristics	Remarks	Min	Typ	Max	Unit
Transmission delay of fault state	Note 22		90		ns
Delay to clear fault state	After IGBT short circuit (Note 23)		9		µs
	After gate-monitoring fault (Notes 23, 27)		1		µs
Acknowledge delay time	Note 24		250		ns
Acknowledge pulse width	On host side	400	700	1050	ns

  

Gate Output	Remarks	Min	Typ	Max	Unit
Turn-on gate resistor $R_{g(on)}$	Note 25		1		Ω
Turn-off gate resistor $R_{g(off)}$	Note 25		7.7		Ω
Auxiliary gate capacitor $C_{ge}$			not assembled		nF
Gate voltage at turn-on	Note 26		15		V
Gate-voltage at turn-off	Note 26		-10		V

### Footnotes to the Key Data

- 1) The transceivers required on the host controller side are not supplied with the gate driver. It is recommended to use the same types as used in the gate driver. For product information refer to [www.power.com/igbt-driver/go/fiberoptics](http://www.power.com/igbt-driver/go/fiberoptics).
- 2) The recommended transmitter current at the host controller is 20mA. A higher current may increase jitter or delay at turn-off.
- 3) The typical transmitter current at the gate driver is 18mA. In case of supply undervoltage, the minimum transmitter current at the gate driver is 12mA: this is suitable for adequate plastic optical fibers with a length of up to 10 meters.
- 4) This refers to the manufacturer ordering number, see [www.power.com/igbt-driver/go/ext\\_erni](http://www.power.com/igbt-driver/go/ext_erni). The customer-side connector as well as cables with different lengths can be supplied by Power Integrations. Refer to the "Description & Application Manual for 1SP0335 SCALE-2 IGBT Drivers" for more information.
- 5) This refers to the manufacturer ordering number, see [www.power.com/igbt-driver/go/ext\\_erni](http://www.power.com/igbt-driver/go/ext_erni). These connectors are to be used to connect 1SP0335x2M1(C) (master) or 1SP0335D2S1(C) (slave) to 1SP0335D2S1(C) (slave) if parallel connection of IGBT modules is required. Cables with different lengths can be supplied by Power Integrations. Refer to the "Description & Application Manual for 1SP0335 SCALE-2 IGBT Drivers" for more information.
- 6) If the specified value is exceeded, this indicates a driver overload. It should be noted that the driver is not protected against overload.
- 7) The given power can only be fully exploited without slaves 1SP0335D2S1(C) (no parallel connection of IGBT modules). If the specified value is exceeded, this indicates a driver overload. It should be noted that the driver is not protected against overload. From 70°C to 85°C, the maximum permissible output power can be linearly interpolated from the given data.
- 8) The given power can be fully exploited with slaves 1SP0335D2S1(C) (parallel connection of IGBT modules). If the specified value is exceeded, this indicates a driver overload. It should be noted that the driver is not protected against overload. From 70°C to 85°C, the maximum permissible output power can be linearly interpolated from the given data.
- 9) The gate current is limited by the gate resistors located on the driver.
- 10) This limit is due to active clamping under switching conditions. Refer to the "Description & Application Manual for 1SP0335 SCALE-2 IGBT Drivers".
- 11) Due to the Dynamic Active Advanced Clamping Function (DA<sup>2</sup>C) implemented on the driver, the DC-link voltage can be increased in the off-state condition (e.g. after emergency shut-down). This value is only valid when the IGBTs are in the off state (not switching). The time during which the voltage can be applied should be limited to short periods (< 60 seconds). Refer to the "Description & Application Manual for 1SP0335 SCALE-2 IGBT Drivers".

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## Data Sheet

- 12) The maximum dynamic voltage between auxiliary emitters of parallel-connected drivers due to asymmetrical operation at turn-on and turn-off must be limited to the given value.
- 13) Maximum allowed rate of change of auxiliary emitter voltage of parallel connected drivers.
- 14) Dynamic voltages between auxiliary emitters of parallel connected drivers at turn-on and turn-off lead to equalizing currents over the X2 or X3 bus. The peak and RMS values of the resulting current must be limited to the given value.
- 15) Undervoltage monitoring of the secondary-side supply voltage (Viso to Vee and Vee to COM which correspond with the approximate turn-on and turn-off gate-emitter voltages). If the corresponding voltage drops below this limit on 1SP0335x2M1(C) (masters), all paralleled IGBTs (master and slaves) are switched off and a fault is transmitted to the status output. If the corresponding voltage drops below this limit on 1SP0335D2S1(C) (slaves), the corresponding IGBT is switched off. If the IGBT was turned on, a fault will be generated by the gate-monitoring function on the master which will turn off all paralleled IGBT after the corresponding delay.
- 16) The mean value  $V_{GE,mean}$  of all gate voltages (master and all slaves) is filtered and compared to the given values at turn-on and turn-off. If the specified values are exceeded ( $V_{GE,mean} < V_{GE,on,min}$  at turn-on resp.  $V_{GE,mean} > V_{GE,off,max}$  at turn-off) after the given filter delay, the driver turns off all parallel-connected IGBTs and a fault is transmitted to the status output.
- 17) A dynamic Vce protection is implemented on the driver. The maximum allowed Vce voltage at turn-on is dynamically adjusted in order to better fit to the IGBT characteristics at turn-on. At the end of the turn-on process the given static value applies.
- 18) The resulting pulse width of the direct output of the gate drive unit for short-circuit type I (excluding the delay of the gate resistors) is the sum of the response time plus the delay to IGBT turn-off.
- 19) The turn-off event of the IGBT is delayed by the specified time after the response time.
- 20) Including the delay of the external fiber-optic links (cable length: 1m). Measured from the transition of the turn-on or turn-off command at the optical transmitter on the host controller side to the direct output of the gate drive unit (excluding the delay of the gate resistors).
- 21) Output rise and fall times are measured between 10% and 90% of the nominal output swing. The values are given for the driver side of the gate resistors with  $2\Omega/1\mu F$  load. The time constant of the output load in conjunction with the present gate resistors leads to an additional delay at their load side.
- 22) Delay of external fiber-optic links. Measured from the driver secondary side (ASIC output) to the optical receiver on the host controller (cable length: 1m).
- 23) Measured on the host side. The fault status on the secondary side is automatically reset after the specified time.
- 24) Including the delay of the external fiber-optic links (cable length: 1m). Measured from the transition of the turn-on or turn-off command at the optical transmitter on the host controller side to the transition of the acknowledge signal at the optical receiver on the host controller side.
- 25) The gate resistors can be leaded or surface mounted. Power Integrations reserves the right to determine which type will be used. Typically, higher quantities will be produced with SMD resistors and small quantities with leaded resistors.
- 26) The driver supply voltage VDC is split into two distinct voltages on the driver. The first one is the turn-on voltage which is regulated at about 15V. The difference between VDC and the turn-on voltage is the turn-off voltage which is not regulated and mainly dependent on the driver input voltage VDC.
- 27) The fault status is set as long as the gate monitoring fault is present. The given value applies if the driver goes from the "off state" to the "on state" and the gate-emitter voltage of one or more parallel connected drivers does not turn on. If the driver goes from the "on state" to the "off state" and the gate-emitter voltage of one or more parallel connected drivers does not turn off, the fault status is applied as long as the gate monitoring fault is present.
- 28) The storage temperature inside the original package (1) or in case the coating material of coated products may touch external parts (2) must be limited to the given value. Otherwise, it is limited to 90°C.
- 29) The component surface temperature, which may strongly vary depending on the operating condition, must be limited to the given value for coated driver versions to ensure long-term reliability of the coating material.

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## Data Sheet

### **Legal Disclaimer**

The statements, technical information and recommendations contained herein are believed to be accurate as of the date hereof. All parameters, numbers, values and other technical data included in the technical information were calculated and determined to our best knowledge in accordance with the relevant technical norms (if any). They may base on assumptions or operational conditions that do not necessarily apply in general. We exclude any representation or warranty, express or implied, in relation to the accuracy or completeness of the statements, technical information and recommendations contained herein. No responsibility is accepted for the accuracy or sufficiency of any of the statements, technical information, recommendations or opinions communicated and any liability for any direct, indirect or consequential loss or damage suffered by any person arising therefrom is expressly disclaimed.

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## Data Sheet

### Ordering Information

Our international terms and conditions of sale apply.

Interface	Power Integrations Driver Type #	Related IGBT
Master, Fiber-Optic Interface <sup>1)</sup>	1SP0335V2M1-FZ750R65KE3	FZ750R65KE3(T)
Master, Fiber-Optic Interface <sup>1), 3)</sup>	1SP0335V2M1C-FZ750R65KE3	FZ750R65KE3(T)
Master, Fiber-Optic Interface <sup>2)</sup>	1SP0335S2M1-FZ750R65KE3	FZ750R65KE3(T)
Master, Fiber-Optic Interface <sup>2), 3)</sup>	1SP0335S2M1C-FZ750R65KE3	FZ750R65KE3(T)
Slave, Electrical Interface	1SP0335D2S1-FZ750R65KE3	FZ750R65KE3(T)
Slave, Electrical Interface <sup>3)</sup>	1SP0335D2S1C-FZ750R65KE3	FZ750R65KE3(T)

<sup>1)</sup> Fiber-optic interface with versatile link (HFBR-2522ETZ and HFBR-1522ETZ)

<sup>2)</sup> Fiber-optic interface with ST (HFBR-2412Z and HFBR-1412Z)

See "Description & Application Manual for 1SP0335 SCALE-2 IGBT Drivers"

<sup>3)</sup> Conformal coated version

Product home page: [www.power.com/igbt-driver/go/1SP0335](http://www.power.com/igbt-driver/go/1SP0335)

Refer to [www.power.com/igbt-driver/go/nomenclature](http://www.power.com/igbt-driver/go/nomenclature) for information on driver nomenclature

### Information about Other Products

**For other drivers, evaluation systems, product documentation and application support**

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## Data Sheet

**Power Integrations Sales Offices**
**WORLD HEADQUARTERS**

5245 Hellyer Avenue  
San Jose, CA 95138 USA  
Tel: +1-408-414-9200  
Fax: +1-408-414-9765  
Email: [usasales@power.com](mailto:usasales@power.com)

**AMERICAS WEST**

5245 Hellyer Avenue  
San Jose, CA 95138 USA  
Tel: +1-408-414-8778  
Fax: +1-408-414-3760  
Email: [usasales@power.com](mailto:usasales@power.com)

**GERMANY** (AC-DC/LED Sales)

Lindwurmstrasse 114  
80337 München, Germany  
Tel: +49-89-5527-39100  
Fax: +49-89-1228-5374  
Email: [eurosales@power.com](mailto:eurosales@power.com)

**INDIA** (Mumbai)

Unit: 106-107, Sagar Tech Plaza-B  
Sakinaka, Andheri Kurla Road  
Mumbai, Maharashtra 400072 India  
Tel 1: +91-22-4003-3700  
Tel 2: +91-22-4003-3600  
Email: [indiasales@power.com](mailto:indiasales@power.com)

**JAPAN**

Kosei Dai-3 Bldg.  
2-12-11, Shin-Yokohama, Kohoku-ku  
Yokohama-shi, Kanagawa  
Japan 222-0033  
Tel: +81-45-471-1021  
Fax: +81-45-471-3717  
Email: [japansales@power.com](mailto:japansales@power.com)

**TAIWAN**

5F, No. 318, Nei Hu Rd., Sec. 1  
Nei Hu Dist.  
Taipei, 114 Taiwan  
Tel: +886-2-2659-4570  
Fax: +886-2-2659-4550  
Email: [taiwansales@power.com](mailto:taiwansales@power.com)

**AMERICAS EAST**

7360 McGinnis Ferry Road  
Suite 225  
Suwannee, GA 30024 USA  
Tel: +1-678-957-0724  
Fax: +1-678-957-0784  
Email: [usasales@power.com](mailto:usasales@power.com)

**CHINA** (Shanghai)

Room 2410, Charity Plaza  
No. 88 North Caoxi Road  
Shanghai, 200030 China  
Tel: +86-21-6354-6323  
Fax: +86-21-6354-6325  
Email: [chinasales@power.com](mailto:chinasales@power.com)

**GERMANY** (Gate Driver Sales)

HellwegForum 1  
59469 Ense, Germany  
Tel: +49-2938-64-39990  
Email: [igbt-driver.sales@power.com](mailto:igbt-driver.sales@power.com)

**INDIA** (New Dehli)

#45, Top Floor  
Okhla Industrial Area, Phase - III  
New Dehli, 110020 India  
Tel 1: +91-11-4055-2351  
Tel 2: +91-11-4055-2353  
Email: [indiasales@power.com](mailto:indiasales@power.com)

**KOREA**

RM602, 6FL, 22  
Teheran-ro 87-gil, Gangnam-gu  
Seoul, 06164 Korea  
Tel: +82-2-2016-6610  
Fax: +82-2-2016-6630  
Email: [koreasales@power.com](mailto:koreasales@power.com)

**UNITED KINGDOM**

Bulding 5, Suite 21  
The Westbrook Centre  
Milton Road  
Cambridge, CB4 1YG United Kingdom  
Tel: +44-7823-557-484  
Email: [eurosales@power.com](mailto:eurosales@power.com)

**AMERICAS CENTRAL**

333 Sheridan Road  
Winnetka, IL 60093 USA  
Tel: +1-847-721-6293  
Email: [usasales@power.com](mailto:usasales@power.com)

**CHINA** (Shenzhen)

17/F, Hivac Building, No 2  
Keji South 8th Road, Nanshan District  
Shenzhen, 518057 China  
Tel: +86-755-8672-8689  
Fax: +86-755-8672-8690  
Email: [chinasales@power.com](mailto:chinasales@power.com)

**INDIA** (Bangalore)

#1, 14th Main Road  
Vasanthangar  
Bangalore, 560052 India  
Tel 1: +91-80-4113-8020  
Tel 2: +91-80-4113-8028  
Fax: +91-80-4113-8023  
Email: [indiasales@power.com](mailto:indiasales@power.com)

**ITALY**

Via Milanese 20  
20099 Sesto San Giovanni (MI), Italy  
Tel: +39-02-4550-8708  
Email: [eurosales@power.com](mailto:eurosales@power.com)

**SINGAPORE**

51 Newton Road  
#19-01/05 Goldhill Plaza  
Singapore, 308900  
Tel 1: +65-6358-2160  
Tel 2: +65-6358-4480  
Fax: +65-6358-2015  
Email: [singaporesales@power.com](mailto:singaporesales@power.com)

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- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



#### Как с нами связаться

**Телефон:** 8 (812) 309 58 32 (многоканальный)

**Факс:** 8 (812) 320-02-42

**Электронная почта:** [org@eplast1.ru](mailto:org@eplast1.ru)

**Адрес:** 198099, г. Санкт-Петербург, ул. Калинина, дом 2, корпус 4, литера А.